

KSB1022

High Power Switching Applications

- High DC Current Gain
- Low Collector-Emitter Saturation Voltage
- Complement to KSD1417



PNP Silicon Darlington Transisto

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	- 60	V
V _{CEO}	Collector-Emitter Voltage	- 60	V
V _{EBO}	Emitter-Base Voltage	- 5	V
I _C	Collector Current (DC)	- 7	Α
I _{CP}	Collector Current (Pulse)	- 10	Α
I _B	Base Current	- 0.7	Α
P _C	Collector Dissipation (T _a =25°C)	2	W
P _C	Collector Dissipation (T _C =25°C)	30	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = -50 \text{mA}, I_B = 0$	- 60			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = -60V, I_{E} = 0$			- 100	μΑ
I _{EBO}	Emitter Cut-off Current	$V_{EB} = -5V, I_{C} = 0$			- 4	mA
h _{FE1} h _{FE2}	DC Current Gain	$V_{CE} = -3V, I_{C} = -3A$ $V_{CE} = -3V, I_{C} = -7A$	2000 1000		15000	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = -3A$, $I_B = -6mA$ $I_C = -7A$, $I_B = -14mA$		- 0.95 - 1.3	- 1.5 - 2	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	$I_C = -3A, I_B = -6mA$		- 1.55	- 2.5	V
t _{ON}	Turn ON Time	V _{CC} = - 45V, I _C = - 3A		0.8		μs
t _{STG}	Storage Time	$I_{B1} = -I_{B2} = -6 \text{mA}$		2		μs
t _F	Fall Time	$R_L = 15\Omega$		2.5		μs

Typical Characteristics

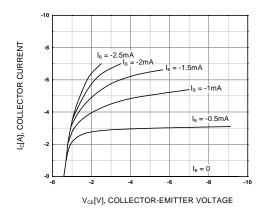


Figure 1. Static Characteristic

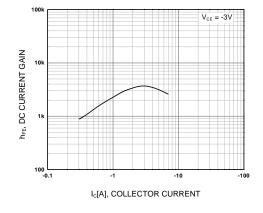


Figure 2. DC current Gain

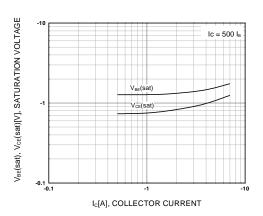


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

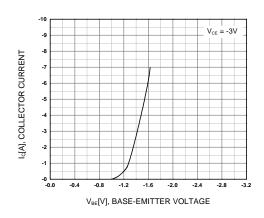


Figure 4. Base-Emitter On Voltage

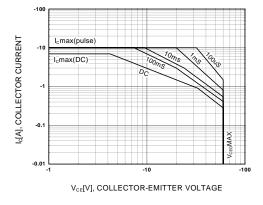


Figure 5. Safe Operating Area

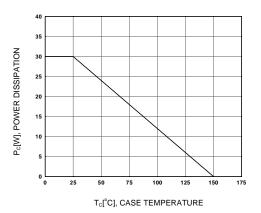
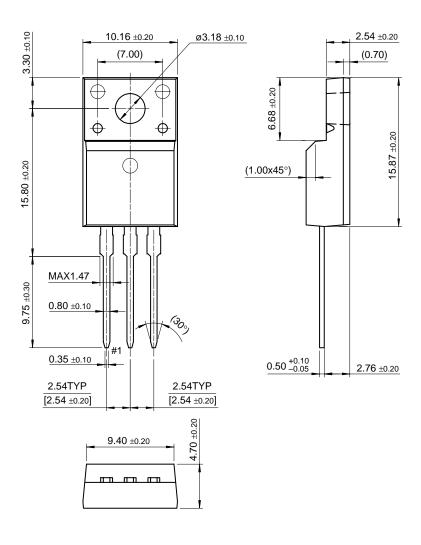


Figure 6. Power Derating

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Package Demensions

TO-220F



Dimensions in Millimeters

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